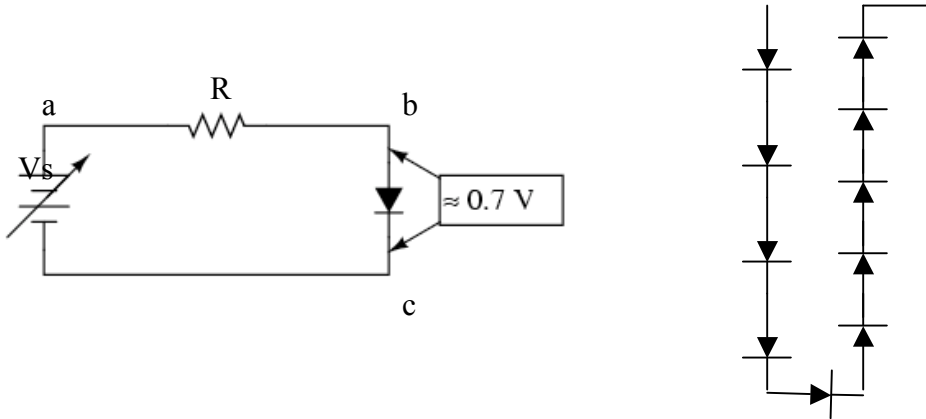


## DIODES for Voltage Regulation

PHYS321

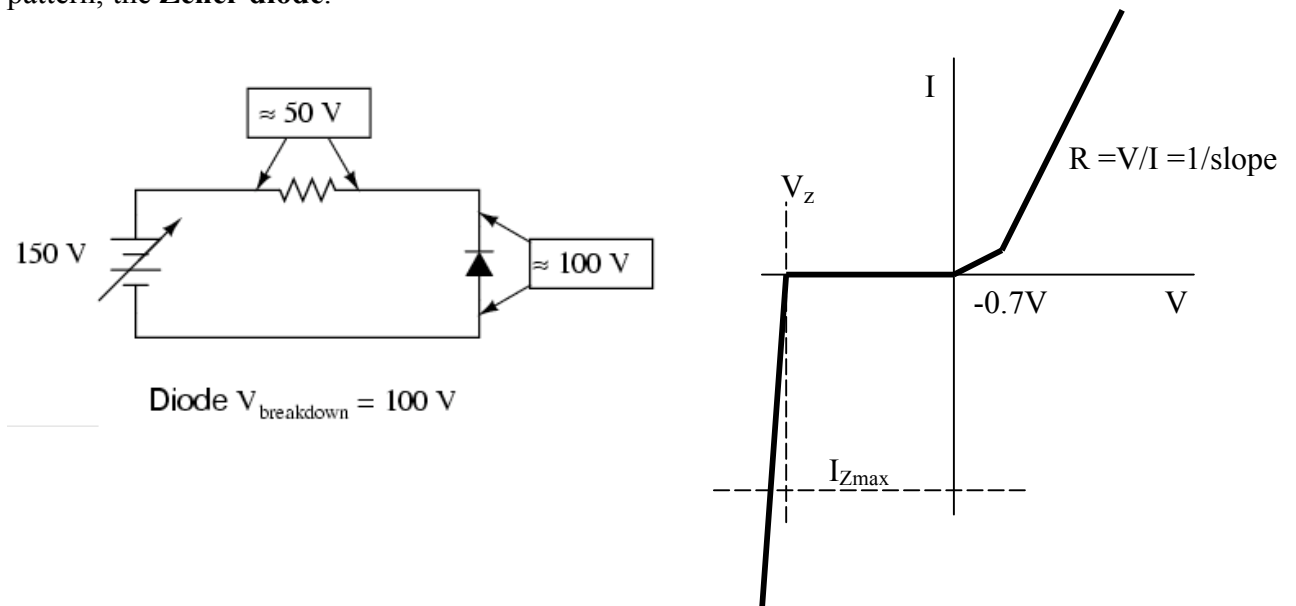
The Si diode exhibits a  $\sim 0.7$  voltage drop in the **forward biased case**. The voltage at b is then  $V_{ab} = 0.7$  V. Point b is fixed to 0.7V independent of current!

The voltage drop across the resistor is  $V_{ba} = V_s - 0.7$ . The current flowing through the resistor is then  $I = (V_a - V_b)/R = (V_s - 0.7)/R$



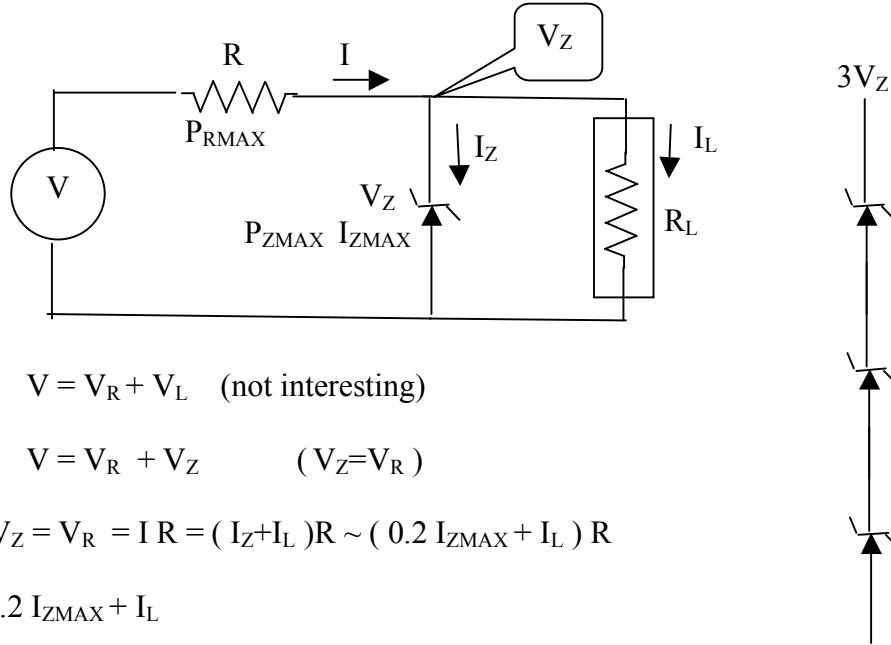
We can add more diodes to the circuit to increase the voltage at point b. If we put 10 diodes in series then  $V_b = 10 \times 0.7 = 7$  V. The current will drop to  $I = (V_s - 7.0)/R$ .

**Reversing the diode.** If we increase the supply voltage (now in the reverse direction) the diode will reach its breakdown voltage  $V_b(\text{reak})$  almost independent of current flow!  $V_b$  is usually 4-100V so a more practical regulation device. Zener realized this property and worked on making diodes which provide a sharp and stable breakdown pattern, the **Zener diode**.



## ZENER DIODE CIRCUIT w LOAD

Imagine we want to design a circuit which keeps the voltage across the load constant. We can use a Zener diode in lower current applications,



1)  $V < V_Z$      $V = V_R + V_L$  (not interesting)

2)  $V > V_Z$      $V = V_R + V_Z$     ( $V_Z = V_R$ )

$$V - V_Z = V_R = I R = (I_Z + I_L) R \sim (0.2 I_{ZMAX} + I_L) R$$

$$I = 0.2 I_{ZMAX} + I_L$$

**Choose:**

$$R = (V - V_Z) / (0.2 I_{ZMAX} + I_L)$$

**Check the power rating on the resistor is not exceeded.**

$$P_R = I^2 R$$

**Check the power rating on the Zener diode is not exceeded.**

$$P_R = I_Z V_Z = (I - I_L) V_Z < P_{ZMAX}$$

### EXAMPLE

With  $V=7V$  design a  $5.1V$  power source capable of supplying  $I_L=10mA$ .

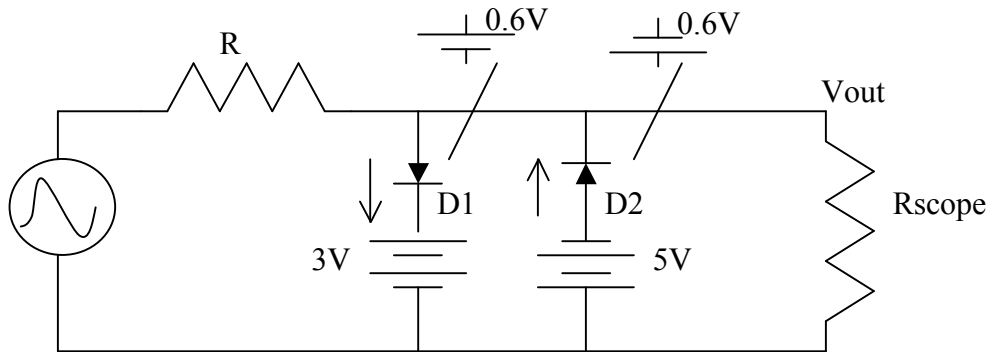
1) Choose a zener diode with ( $V_Z=5.1V$   $I_{ZMAX}=50mA$ )

2)  $R = 1.9V/20mA = 95\Omega$

$$P_R = (0.020A)^2 \cdot 95\Omega = 38mW \quad (\text{Can use } 100\Omega \text{ } 1/4W)$$

3)  $P_Z = I_Z V_Z = (0.010A)(5.1V) = 5.1mW = 1/5 I_{ZMAX} V_Z$

## Analysis of a Diode Clipper Circuit

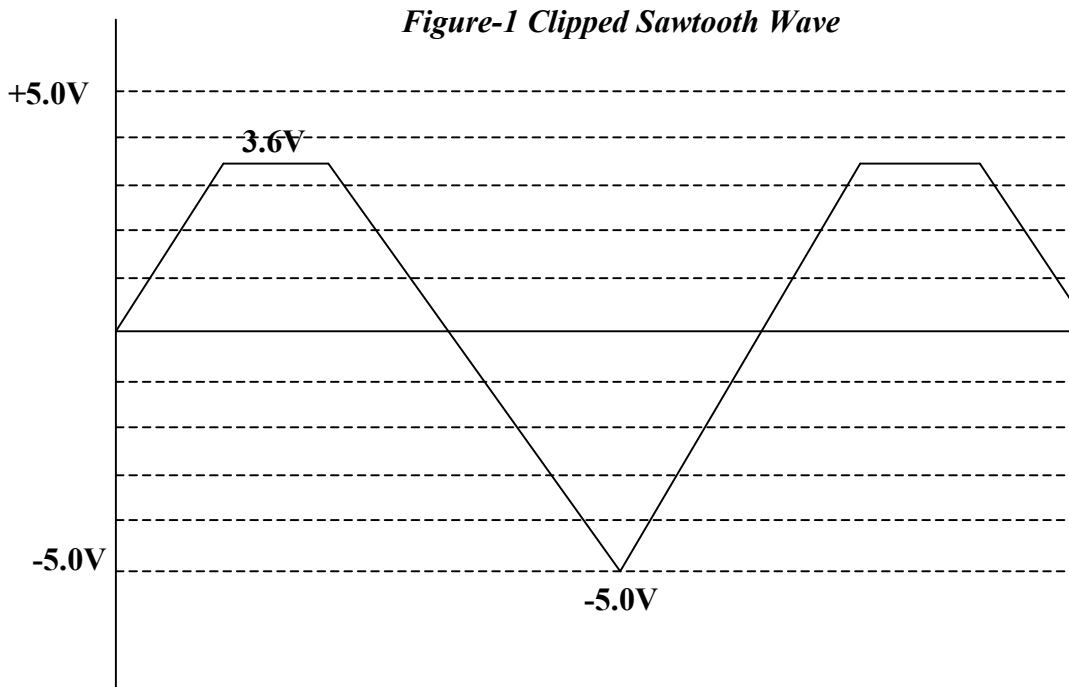


Both diodes are reversed biased by the batteries in the circuit. Until the input voltage exceeds the battery voltage + 0.6V diode drop in both cases no current will flow through the diodes D1 or D2. All the current flows through Rscope! The scope will see the input voltage rise and fall during this period (Rscope >> R).

$$V_{out} = V_{in} \left( \frac{R_{scope}}{R_{scope} + R} \right) \cong V_{in} \quad \text{-voltage divider}$$

On the positive half-cycle when  $+|V_{in}| > 3V + 0.6V$  the diode conducts and all current flows through D1, none through D2. (A small amount through Rscope!) The diode is now like the 0.6V battery depicted above.

On the negative half-cycle D2 conducts when  $-|V_{in}| < 5V + 0.6V$  or  $V_{in} < -5.6V$ . This condition is never reached and the negative input signal is seen on the scope unclipped!



## Cockroft Walton Voltage Multipliers

The classic multistage diode/capacitor voltage multiplier, popularized by Cockroft and Walton, is probably the most popular means of generating high voltages at low currents at low cost. It is used in virtually every television set made to generate the 20-30 kV second anode accelerating voltage from a transformer putting out 10-15 kV pulses. It has the advantage of requiring relatively low cost components and being easy to insulate. It also inherently produces a series of stepped voltages which is useful in some forms of particle accelerators, and for biasing photomultiplier tube dynodes.

The CW multiplier has the disadvantage of having very poor voltage regulation, that is, the voltage drops rapidly as a function the output current. In some applications, this is an advantage. The output V/I characteristic is roughly hyperbolic, so it serves well for charging capacitor banks to high voltages at roughly constant charging power. Furthermore, the ripple on the output, particularly at high loads, is quite high.

It is quite popular for relatively low powered particle accelerators for injecting into another accelerator, particularly for heavy ions. The high ripple means that there is a significant energy spread in the ion beam, though, and for applications where low ripple is important at megavolt potentials, electrostatic systems like Van de Graaf and Pelletron machines are preferred

